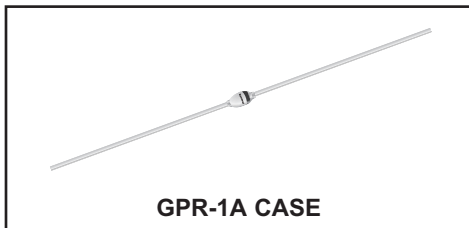


1N5059 1N5061  
1N5060 1N5062

**GLASS PASSIVATED  
SILICON RECTIFIERS  
1.0 AMP, 200 THRU 800 VOLT**



[www.centrasemi.com](http://www.centrasemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 1N5059 series types are silicon rectifiers manufactured in a hermetically sealed, glass passivated package, designed for general purpose applications where high reliability is desired. Higher voltage devices are available in the CPR1-010 series.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

	<b>SYMBOL</b>	<b>1N5059</b>	<b>1N5060</b>	<b>1N5061</b>	<b>1N5062</b>	<b>UNITS</b>
Peak Repetitive Reverse Voltage	$V_{RRM}$	200	400	600	800	V
DC Blocking Voltage	$V_R$	200	400	600	800	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	280	420	560	V
Average Forward Current ( $T_A=75^\circ\text{C}$ )	$I_O$			1.0		A
Peak Forward Surge Current, $t_p=8.3\text{ms}$	$I_{FSM}$			40		A
Operating and Storage Junction Temperature	$T_J, T_{stg}$			-65 to +175		$^\circ\text{C}$
Thermal Resistance	$\Theta_{JA}$			40		$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

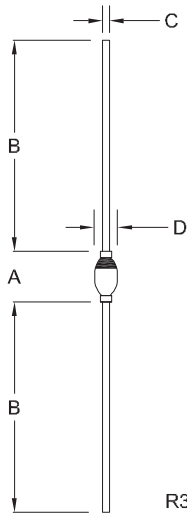
<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MAX</b>	<b>UNITS</b>
$I_R$	$V_R=\text{Rated } V_{RRM}$	5.0	$\mu\text{A}$
$I_R$	$V_R=\text{Rated } V_{RRM}, T_A=175^\circ\text{C}$ (1N5059, 1N5060)	300	$\mu\text{A}$
$I_R$	$V_R=\text{Rated } V_{RRM}, T_A=175^\circ\text{C}$ (1N5061, 1N5062)	200	$\mu\text{A}$
$V_F$	$I_F=1.0\text{A}$	1.2	V
$C_J$	$V_R=4.0\text{V}, f=1.0\text{MHz}$	15	pF

1N5059 1N5061  
1N5060 1N5062

GLASS PASSIVATED  
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GPR-1A CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	-	0.240	-	6.10
B	1.000	-	25.40	-
C	0.028	0.034	0.71	0.86
D	0.070	0.150	1.80	3.81

GPR-1A (REV: R3)

MARKING: FULL PART NUMBER

R5 (28-February 2013)